NSN 5962-01-365-2257

Memory Microcircuit - Page 1 of 1



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## **Maximum Power Dissipation Rating:** 550.0 milliwatts **Operating Tempurature Range:** -65.0/+150.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Burn in and monolithic and programmed and electrostatic sensitive and ultraviolet erasable **Inclosure Material:** Ceramic **Inclosure Configuration:** Leadless flat pack **Output Logic Form:** Complementary-metal oxide-semiconductor logic **Input Circuit Pattern:** 14 input **Case Outline Source And Designator:** C-12 mil-m-38510 **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: -2.0 volts power source and 7.0 volts power source **Time Rating Per Chacteristic:** 90.00 nanoseconds propagation delay Memory Device Type: Eprom **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 32 leadless Shelf Life: Unit Of Measure: **Demilitarization:** Yes - demil/mli A458a0

N/a

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